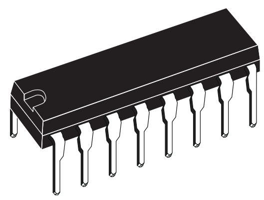
ULN2001A-ULN2002A
ULN2003A-ULN2004A

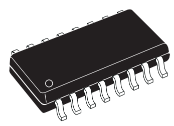
SEVEN DARLINGTON ARRAYS

- SEVEN DARLINGTONS PER PACKAGE
- OUTPUT CURRENT 500mA PER DRIVER (600mA PEAK)
- OUTPUT VOLTAGE 50V
- INTEGRATED SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL/CMOS/PMOS/DTL COMPATIBLE INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT



DIP16

ORDERING NUMBERS: ULN2001A/2A/3A/4A



SO16

ORDERING NUMBERS: ULN2001D/2D/3D/4D

DESCRIPTION

The ULN2001A, ULN2002A, ULN2003 and ULN2004A are high voltage, high current darlington arrays each containing seven open collector darlington pairs with common emitters. Each channel rated at 500mA and can withstand peak currents of 600mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

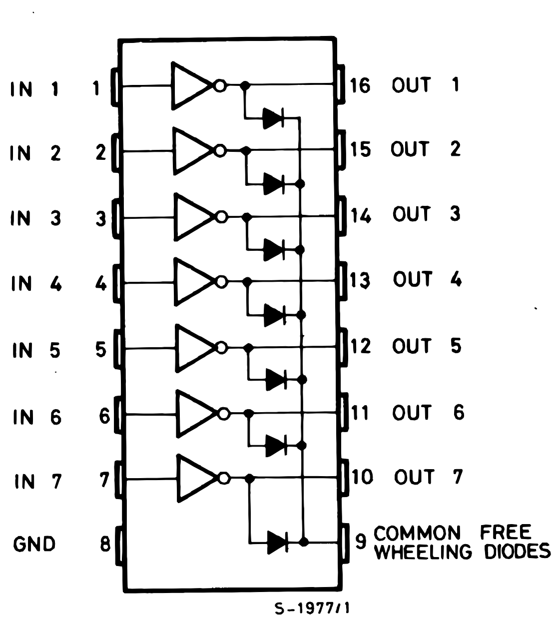
The four versions interface to all common logic families :

ULN2001A	General Purpose, DTL, TTL, PMOS, CMOS
ULN2002A	14-25V PMOS
ULN2003A	5V TTL, CMOS
ULN2004A	6–15V CMOS, PMOS

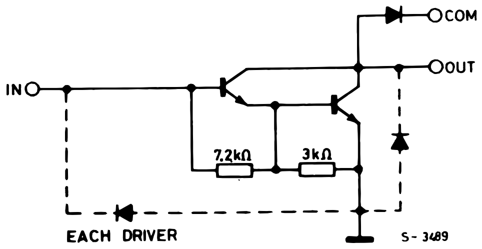
These versatile devices are useful for driving a wide range of loads including solenoids, relays DC motors, LED displays filament lamps, thermal printheads and high power buffers.

The ULN2001A/2002A/2003A and 2004A are supplied in 16 pin plastic DIP packages with a copper leadframe to reduce thermal resistance. They are available also in small outline package (SO-16) as ULN2001D/2002D/2003D/2004D.

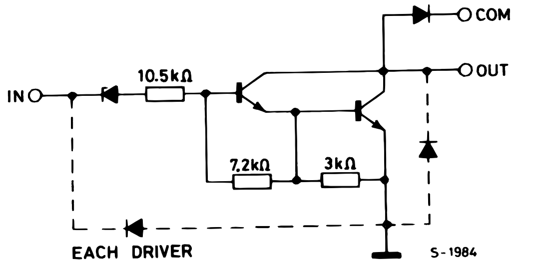
PIN CONNECTION



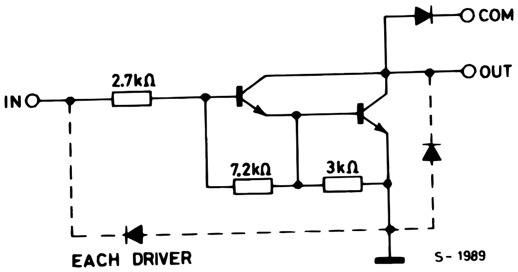
SCHEMATIC DIAGRAM



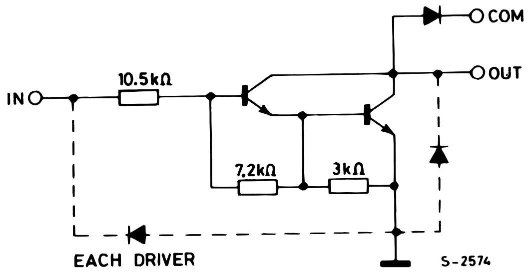
Series ULN-2001A
(each driver)



Series ULN-2002A
(each driver)



Series ULN-2003A
(each driver)



Series ULN-2004A
(each driver)

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_o	Output Voltage	50	V
V_{in}	Input Voltage (for ULN2002A/D - 2003A/D - 2004A/D)	30	V
I_c	Continuous Collector Current	500	mA
I_b	Continuous Base Current	25	mA
T_{amb}	Operating Ambient Temperature Range	– 20 to 85	°C
T_{stg}	Storage Temperature Range	– 55 to 150	°C
T_j	Junction Temperature	150	°C

THERMAL DATA

Symbol	Parameter		DIP16	SO16	Unit
$R_{th\ j\text{-}amb}$	Thermal Resistance Junction-ambient	Max.	70	120	°C/W

ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
I_{CEX}	Output Leakage Current	V_{CE} = 50V T_{amb} = 70°C, V_{CE} = 50V T_{amb} = 70°C for ULN2002A V_{CE} = 50V, V_i = 6V for ULN2004A V_{CE} = 50V, V_i = 1V			50 100 500 500	µA µA µA µA	1a 1a 1b 1b
$V_{CE(sat)}$	Collector-emitter Saturation Voltage	I_C = 100mA, I_B = 250µA I_C = 200 mA, I_B = 350µA I_C = 350mA, I_B = 500µA		0.9 1.1 1.3	1.1 1.3 1.6	V V V	2 2 2
$I_{i(on)}$	Input Current	for ULN2002A, V_i = 17V for ULN2003A, V_i = 3.85V for ULN2004A, V_i = 5V V_i = 12V		0.82 0.93 0.35 1	1.25 1.35 0.5 1.45	mA mA mA mA	3 3 3 3
$I_{i(off)}$	Input Current	T_{amb} = 70°C, I_C = 500µA	50	65		µA	4
$V_{i(on)}$	Input Voltage	V_{CE} = 2V for ULN2002A I_C = 300mA for ULN2003A I_C = 200mA I_C = 250mA I_C = 300mA for ULN2004A I_C = 125mA I_C = 200mA I_C = 275mA I_C = 350mA			 13 2.4 2.7 3 5 6 7 8	V	5
h_{FE}	DC Forward Current Gain	for ULN2001A V_{CE} = 2V, I_C = 350mA	 1000				 2
C_i	Input Capacitance			15	25	pF	
t_{PLH}	Turn-on Delay Time	0.5 V_i to 0.5 V_o		0.25	1	µs	
t_{PHL}	Turn-off Delay Time	0.5 V_i to 0.5 V_o		0.25	1	µs	
I_R	Clamp Diode Leakage Current	V_R = 50V T_{amb} = 70°C, V_R = 50V			50 100	µA µA	6 6
V_F	Clamp Diode Forward Voltage	I_F = 350mA		1.7	2	V	7

TEST CIRCUITS

Figure 1a.

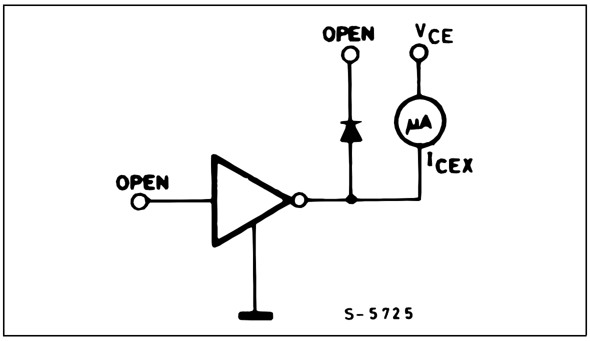


Figure 1b.

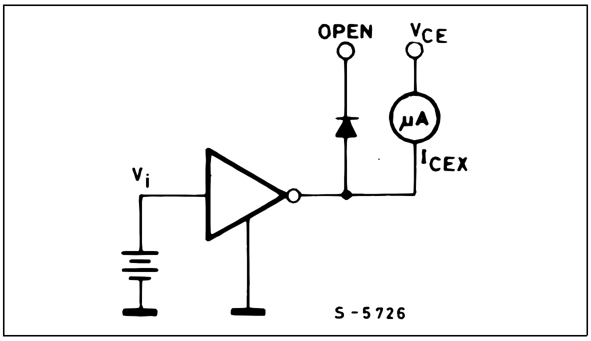


Figure 2.

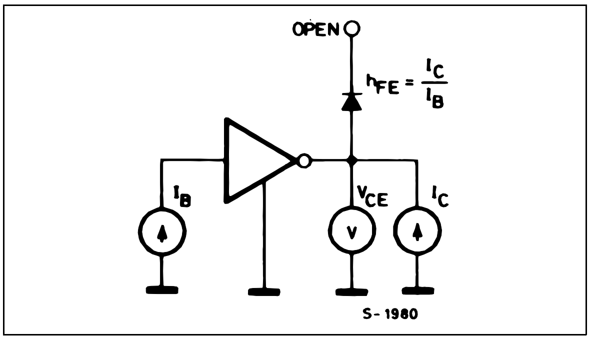


Figure 3.

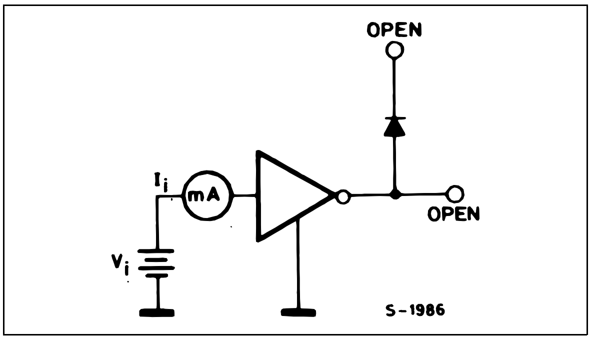


Figure 4.

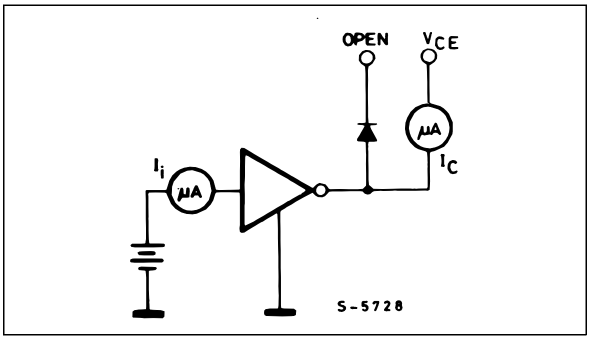


Figure 5.

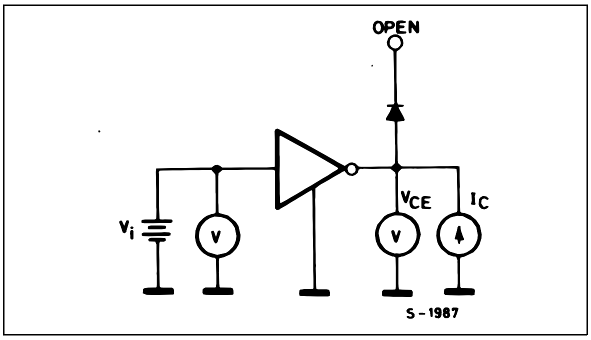


Figure 6.

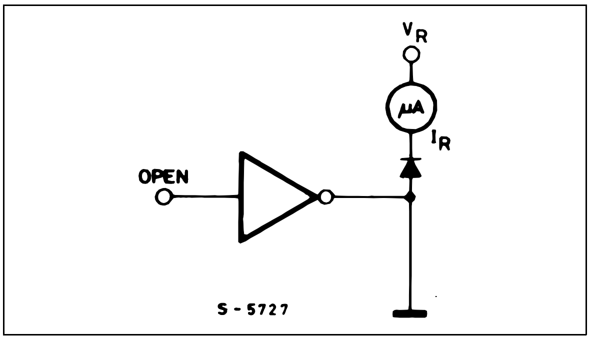


Figure 7.

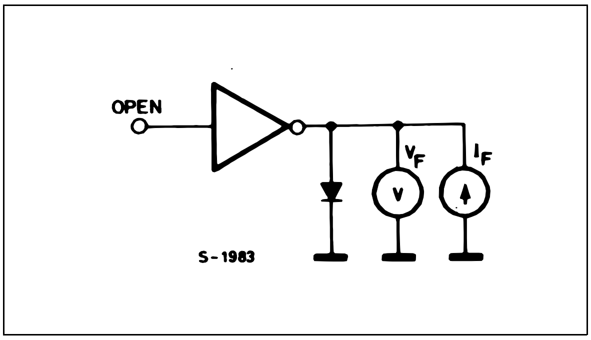


Figure 8: Collector Current versus Input Current

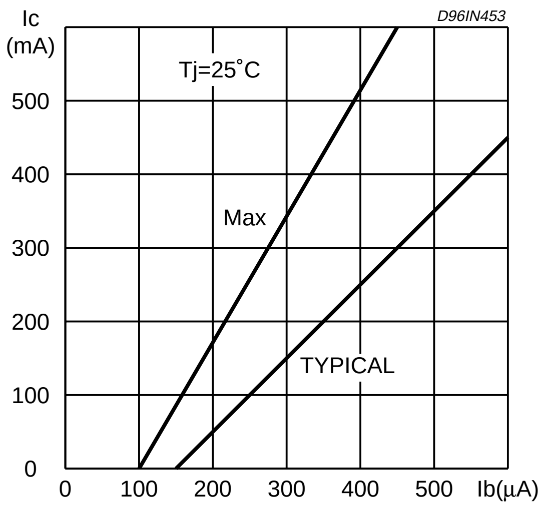


Figure 9: Collector Current versus Saturation Voltage

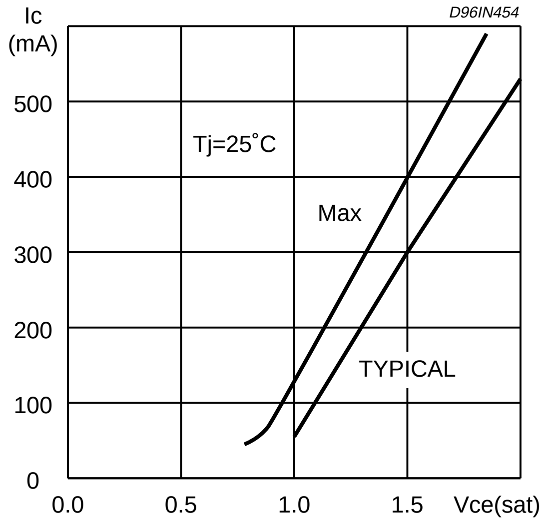


Figure 10: Peak Collector Current versus Duty Cycle

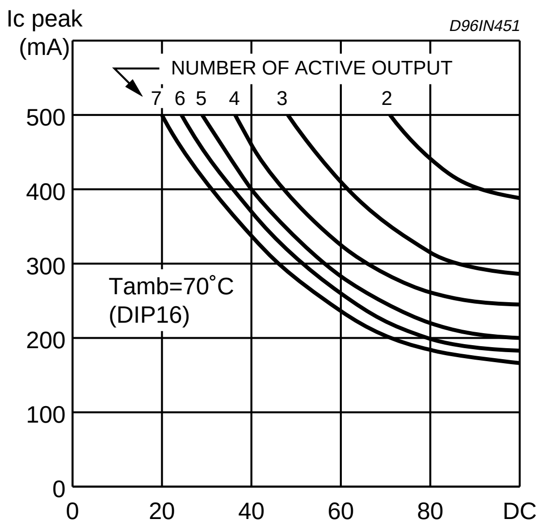
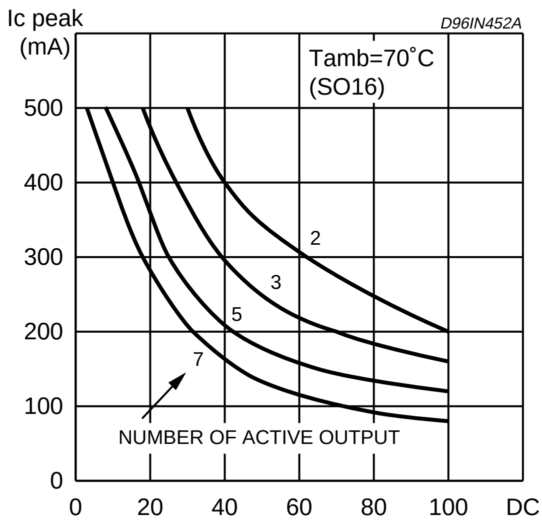
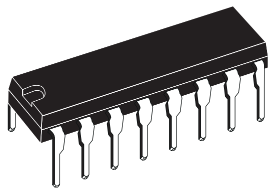


Figure 11: Peak Collector Current versus Duty Cycle

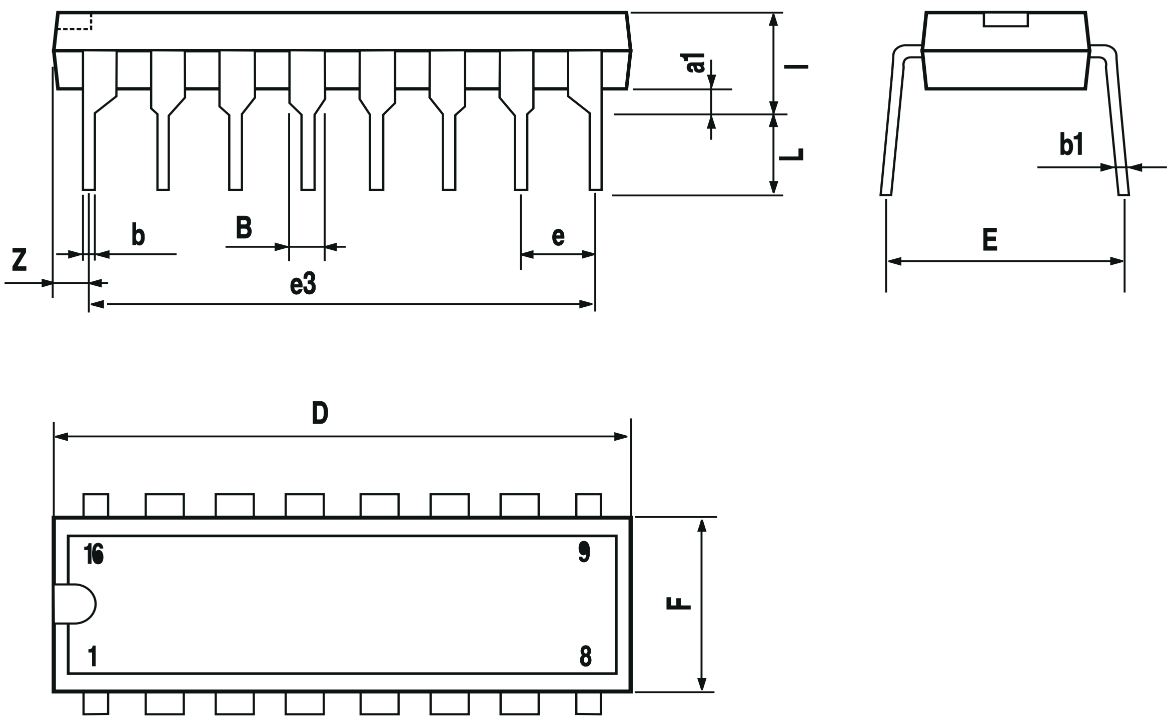


DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

OUTLINE AND MECHANICAL DATA

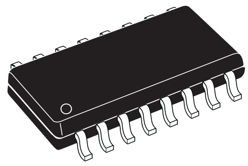


DIP16



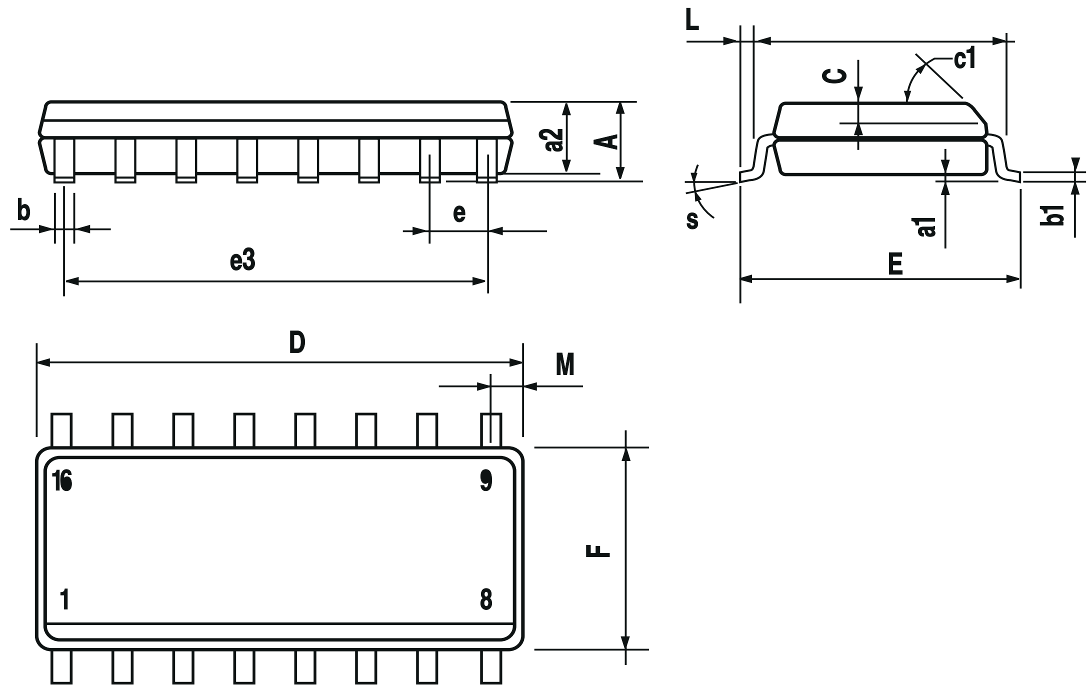
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.009
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45˚ (typ.)					
D (1)	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F (1)	3.8		4	0.150		0.157
G	4.6		5.3	0.181		0.209
L	0.4		1.27	0.016		0.050
M			0.62			0.024
S	8˚(max.)					

OUTLINE AND MECHANICAL DATA



SO16 Narrow

(1) D and F do not include mold flash or protrusions. Mold flash or potrusions shall not exceed 0.15mm (.006inch).



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